

# **Schottky Barrier Rectifiers**

Using the Schottky Barrier principle with appropriate barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

- \*Low Forward Voltage.
- \*Low Switching noise.
- \* High Current Capacity
- \* Guarantee Reverse Avalanche.
- \* Guard-Ring for Stress Protection.
- \*Low Power Loss & High efficiency.
- \* High Operating Junction Temperature
- \*Low Stored Charge Majority Carrier Conduction.
- \* Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- \*Pb free
- \* In compliance with EU RoHs directives





#### MAXIMUM RATINGS

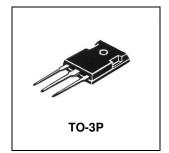
Characteristic	Symbol	S60D100C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	100	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	70	V
Average Rectifier Forward Current (per diode) Total Device (Rated V <sub>R</sub> )	I <sub>F(AV)</sub>	30 60	Α
Peak Repetitive Forward Current (Rate V <sub>R</sub> , Square Wave, 20kHz)	I <sub>FM</sub>	60	Α
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-ware, single phase, 60Hz)	I <sub>FSM</sub>	400	А
Operating and Storage Junction Temperature Range	$T_J$ , $T_{STG}$	-65 to +150	$^{\circ}\! \mathbb{C}$

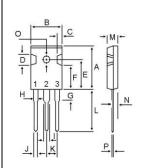
# **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage ( $I_F = 30 \text{ Amp } T_C = 25^{\circ}C$ ) ( $I_F = 30 \text{ Amp } T_C = 125^{\circ}C$ )	V <sub>F</sub>		0.80 0.65	0.9	٧
Maximum Instantaneous Reverse Current (Rated DC Voltage, T <sub>C</sub> = 25°C) (Rated DC Voltage, T <sub>C</sub> = 125°C)	I <sub>R</sub>		0.0002 0.4	3.0	mA

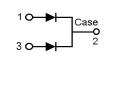
# SCHOTTKY BARRIER RECTIFIERS

60 AMPERES 100 VOLTS

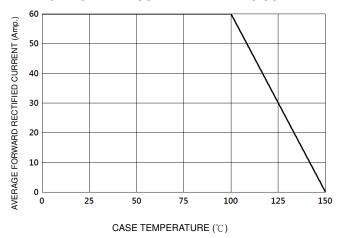




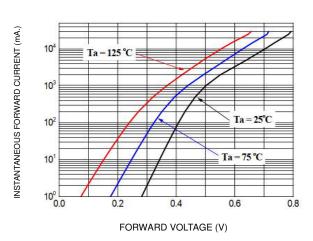
DIM	MILLIMETERS		
	MIN	MAX	
Α	20.80	21.80	
В	15.38	16.20	
С	1.90	2.70	
D	5.10	6.10	
Ε	14.50	15.50	
F	11.20	13.20	
G	3.75	4.35	
Н	1.90	2.30	
- 1	2.90	3.30	
J	1.00	1.40	
K	5.26	5.66	
L	19.50	20.50	
M	4.68	5.36	
Ν	2.30	2.60	
0	3.45	3.85	
Р	0.48	0.72	



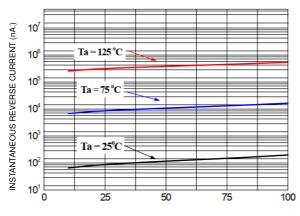
# FIG-1 FORWARD CURRENT DERATING CURVE



#### FIG-2 TYPICAL FORWARD CHARACTERISTICS

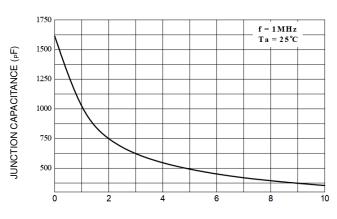


# FIG-3 TYPICAL REVERSE CHARACTERISTICS



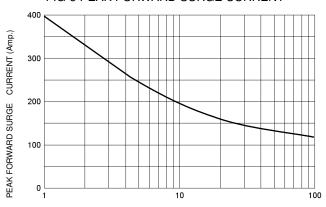
PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

# FIG-4 TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE (V)

# FIG-5 PEAK FORWARD SURGE CURRENT



NUMBER OF CYCLES AT 60 Hz



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